BLF7G20L-250P; BLF7G20LS-250P Power LDMOS transistor Rev. 5 — 1 September 2015

AMMPLEON

Product data sheet

Product profile

1.1 General description

250 W LDMOS power transistor for base station applications at frequencies from 1805 MHz to 1880 MHz.

Typical performance Table 1.

Typical RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Mode of operation	f	I _{Dq}	V _{DS}	$P_{L(AV)}$	Gp	η_D	ACPR
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	1805 to 1880	1900	28	70	18	35	-29.5 <mark>[1]</mark>

^[1] Test signal: 3GPP; test model 1;64 DPCH; PAR = 8.4 dB at 0.01% probability on CCDF.

1.2 Features and benefits

- Excellent ruggedness
- High-efficiency
- Low R_{th} providing excellent thermal stability
- Designed for broadband operation (1805 MHz to 1880 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

1.3 Applications

RF power amplifiers for W-CDMA base stations and multicarrier applications in the 1805 MHz to 1880 MHz frequency range

2. Pinning information

Table 2. Pinning

Table 2.	i iiiiiiig		
Pin	Description	Simplified outline	Graphic symbol
BLF7G20	L-250P (SOT539A)		
1	drain1		
2	drain2	1 2	<u>1</u> ا
3	gate1		5
4	gate2	3 4	5
5	source	[1]	4
			,
			sym117

BLF7G2	20LS-250P (SOT539B)			
1	drain1			
2	drain2		1 2 5	1
3	gate1			
4	gate2		3 4	3 - 5
5	source	[1]		2 sym117

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BLF7G20L-250P	-	flanged balanced LDMOST ceramic package; 2 mounting holes; 4 leads	SOT539A			
BLF7G20LS-250P	-	earless flanged balanced LDMOST ceramic package; 4 leads	SOT539B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
I _D	drain current		-	65	Α
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	200	°C

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5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T_{case} = 80 °C; P_{L} = 70 W; V_{DS} = 28 V; I_{Dq} = 1900 mA; $T_{j} \le$ 150 °C	0.20	K/W

6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C unless otherwise specified.

J						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.5 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 150 mA	1.5	1.78	2.3	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	33.4	37.54	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	68.3	-	nA
g _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 7.5 A	-	12.37	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 5.25 \text{ A}$	-	0.078	0.135	Ω

7. Test information

Table 7. 2-carrier W-CDMA functional test information

Class-AB production test circuit; PAR = 8.4 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 64 DPCH; f = 1805 MHz to 1880 MHz; RF performance at $V_{DS} = 28$ V; $I_{Dg} = 1900$ mA; $T_{case} = 25$ °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_{L(AV)}$	average output power		-	70	-	W
Gp	power gain	$P_{L(AV)} = 70 W$	16	18	-	dB
RLin	input return loss	$P_{L(AV)} = 70 W$	-	-12	-	dB
η_{D}	drain efficiency	$P_{L(AV)} = 70 W$	30	35	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)} = 70 W$	-	-29.5	-24.5	dBc

7.1 Ruggedness in class-AB operation

The BLF7G20L-250P and BLF7G20LS-250P are capable of withstanding a load mismatch corresponding to a VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 1900 mA; $P_{L(1dB)}$ = 245 W (CW); f = 1805 MHz to 1880 MHz.

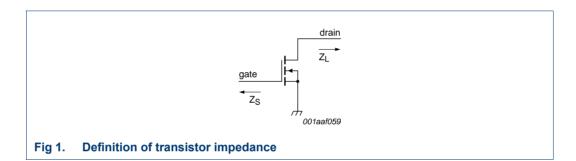
7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data half device; $I_{Dq} = 950 \text{ mA}$; $V_{DS} = 28 \text{ V}$.

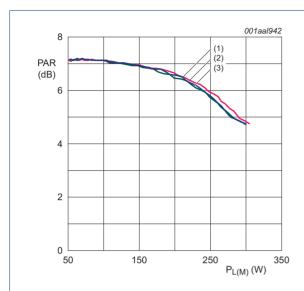
f	Z _S [1]	Z _L [1]
(MHz)	(Ω)	(Ω)
1750	1.31 – j3.53	2.47 – j3.91
1805	1.39 – j3.75	2.27 – j3.63
1845	1.48 – j4.10	2.32 – j3.19
1880	1.55 – j4.19	1.89 – j3.15
1930	1.97 – j4.48	1.70 – j2.95

[1] Z_S and Z_L defined in Figure 1.



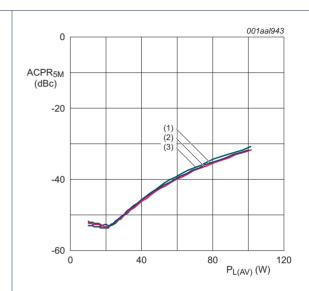
7.3 Single carrier W-CDMA

3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz; channel spacing = 5 MHz; V_{DS} = 28 V; I_{Dg} = 1900 mA



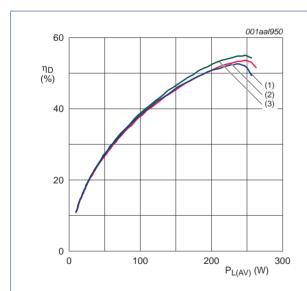
- (1) f = 1805 MHz.
- (2) f = 1845 MHz.
- (3) f = 1880 MHz.

Fig 2. Peak-to-average power ratio as a function of peak output power; typical values



- (1) f = 1805 MHz.
- (2) f = 1845 MHz.
- (3) f = 1880 MHz.

Fig 3. Adjacent channel power ratio (5 MHz) as a function of average output power; typical values



- (1) f = 1805 MHz.
- (2) f = 1845 MHz.
- (3) f = 1880 MHz.

Fig 4. Efficiency as a function of average output power; typical values

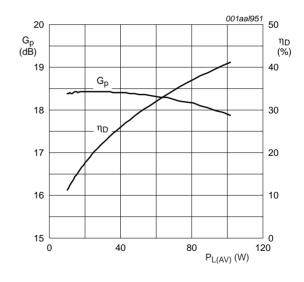
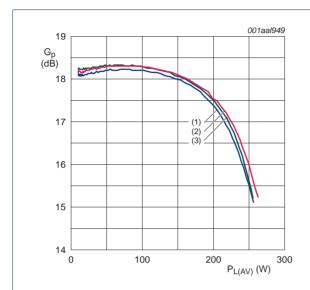


Fig 5. Power gain and drain efficiency as a function of average output power; typical values

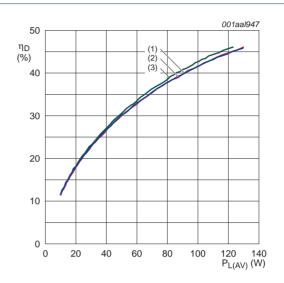
7.4 One tone CW

 $V_{DS} = 28 \text{ V}; I_{Dq} = 1900 \text{ mA}.$



- (1) f = 1805 MHz.
- (2) f = 1845 MHz.
- (3) f = 1880 MHz.

Fig 6. Power gain as a function of average output power; typical values

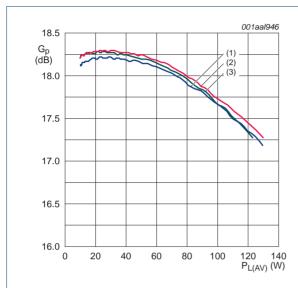


- (1) f = 1805 MHz.
- (2) f = 1845 MHz.
- (3) f = 1880 MHz.

Fig 7. Efficiency as a function of average output power; typical values

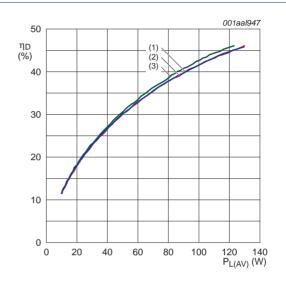
7.5 2-carrier WCDMA characteristics

 V_{DS} = 28 V; I_{Dq} = 1900 mA; channel spacing = 5 MHz; PAR = 8.4 dB at 0.01 % probability on the CCDF.



- (1) f = 1805 MHz.
- (2) f = 1845 MHz.
- (3) f = 1880 MHz.

Fig 8. Power gain as a function of average output power; typical values



- (1) f = 1805 MHz.
- (2) f = 1845 MHz.
- (3) f = 1880 MHz.

Fig 9. Efficiency as a function of average output power; typical values

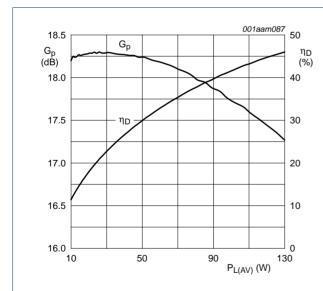
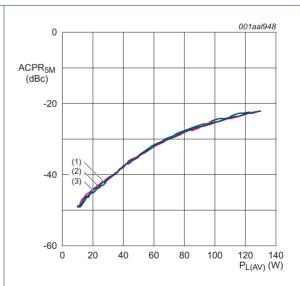


Fig 10. Average power gain and drain efficiency as a function of average output power; typical values



- (1) f = 1805 MHz.
- (2) f = 1845 MHz.
- (3) f = 1880 MHz.

Fig 11. Adjacent channel power ratio (5 MHz) as a function of average output power; typical values

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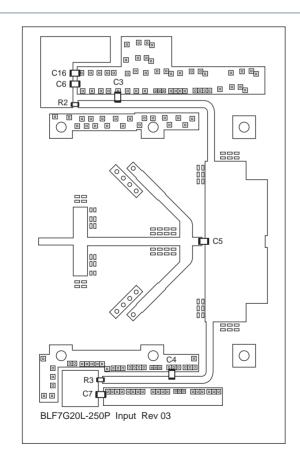
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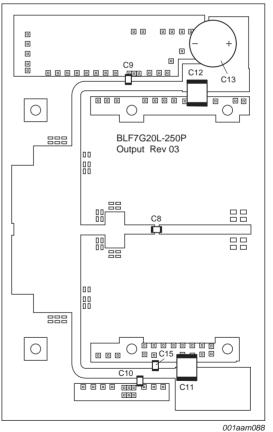
7.6 Test circuit

Table 9. List of components For test circuit see Figure 12.

1 11 30 011 001					
Component	Description	Value	Code number	Type	Remarks
Base plate [П				
C3, C4, C9, C10	multi layer ceramic chip capacitor	47 pF		ATC 800B	mount on edge
C5	multi layer ceramic chip capacitor	1.2 pF		ATC 800B	mount on edge
C6, C7	chip capacitor	560 pF		ATC 100A	
C8	multi layer ceramic chip capacitor	68 pF		ATC 800B	mount on edge
C11, C12	multi layer ceramic chip capacitor	10 μF		TDK	
C13	electrolytic capacitor	470 μF; 63 V			
C15, C16	multi layer ceramic chip capacitor	100 nF		Phillips 1206	
R2, R3	chip resistor	10 Ω		Philips 0603	

[1] See mechanical drawing (Figure 12).





Printed-Circuit Board (PCB): Taconic RF35; ϵr = 3.5 F/m; thickness = 0.76 mm; thickness copper plating = 35 μ m See Table 9 for a list of components.

Fig 12. Component layout for class-AB production test circuit

8. Package outline

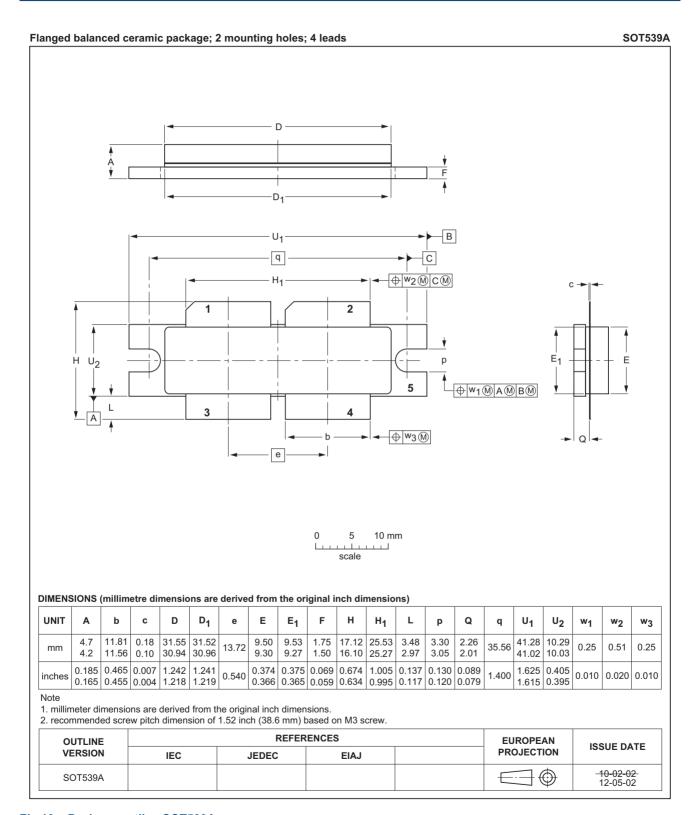


Fig 13. Package outline SOT539A

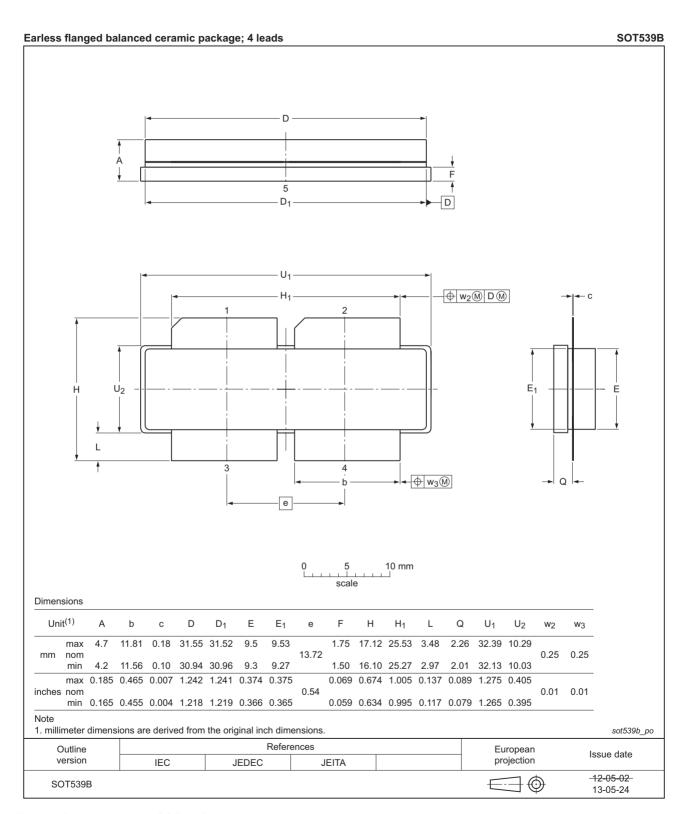


Fig 14. Package outline SOT539B

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
PAR	Peak-to-Average power Ratio
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF7G20L-250P_7G20LS-250P#5	20150901	Product data sheet	-	BLF7G20L-250P_7G20LS-250P v.4	
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 				
	 Legal te 	exts have been adapted	to the new	company name where appropriate.	
BLF7G20L-250P_7G20LS-250P v.4	20130712	Product data sheet	-	BLF7G20L-250P_7G20LS-250P v.3	
BLF7G20L-250P_7G20LS-250P v.3	20110103	Product data sheet	-	BLF7G20L-250P_7G20LS-250P v.2	
BLF7G20L-250P_7G20LS-250P v.2	20100909	Preliminary data sheet	-	BLF7G20L-250P_7G20LS-250P v.1	
BLF7G20L-250P_7G20LS-250P v.1	20091216	Objective data sheet	-	-	

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
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Power LDMOS transistor

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Power LDMOS transistor

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